## SN74ALVCH16823 18-BIT BUS-INTERFACE FLIP-FLOP WITH 3-STATE OUTPUTS

SCES038F-JULY 1995-REVISED APRIL 2005

#### **FEATURES**

- Member of the Texas Instruments Widebus™
   Family
- EPIC<sup>™</sup> (Enhanced-Performance Implanted CMOS) Submicron Process
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages

#### DESCRIPTION

This 18-bit bus-interface flip-flop is designed for 1.65-V to 3.6-V  $V_{\rm CC}$  operation.

The SN74ALVCH16823 features 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. This device is particularly suitable for implementing wider buffer registers, I/O ports, bidirectional bus drivers with parity, and working registers.

The SN74ALVCH16823 can be used as two 9-bit flip-flops or one 18-bit flip-flop. With the clock-enable (CLKEN) input low, the D-type flip-flops enter data on the low-to-high transitions of the clock. Taking CLKEN high disables the clock buffer, thus latching the outputs. Taking the clear (CLR) input low causes the Q outputs to go low independently of the clock.

#### DGG OR DL PACKAGE (TOP VIEW)

_	_	U		L
1CLR	1	$\overline{}$	56	]1CLK
1 <u>OE</u> [	2		55	1CLKEN
1Q1 [	3		54	]1D1
GND [	4		53	GND
1Q2	5		52	]1D2
1Q3	6		51	] 1D3
V <sub>CC</sub>	7		50	]v <sub>cc</sub>
1Q4	8		49	]1D4
1Q5	9		48	] 1D5
1Q6	10		47	]1D6
GND [	11		46	GND
1Q7	12		45	] 1D7
1Q8	13		44	] 1D8
1Q9	14		43	] 1D9
2Q1	15		42	]2D1
2Q2 [	16		41	]2D2
2Q3	17		40	]2D3
GND [	18		39	GND
2Q4 [	19		38	2D4
2Q5	20		37	2D5
2Q6	21		36	]2D6
V <sub>CC</sub>	22		35	]∨ <sub>cc</sub>
2Q7 [	23		34	2D7
2Q8	24		33	2D8
GND [	25		32	GND
2Q9 [	26		31	2D9
2 <del>OE</del>	27		30	2CLKEN
2CLR	28		29	2CLK

A buffered output-enable  $(\overline{OE})$  input can be used to place the nine outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

The output-enable ( $\overline{OE}$ ) input does not affect the internal operation of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN74ALVCH16823 is characterized for operation from -40°C to 85°C.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

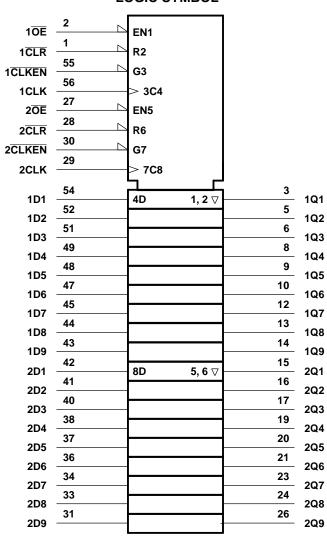
Widebus, EPIC are trademarks of Texas Instruments.



## FUNCTION TABLE (each 9-bit flip-flop)

		INPUTS			OUTPUT
ŌĒ	CLR	CLKEN	CLK	D	Q
L	L	Χ	Χ	Χ	L
L	Н	L	$\uparrow$	Н	Н
L	Н	L	$\uparrow$	L	L
L	Н	L	L	Χ	$Q_0$
L	Н	Н	Χ	Χ	$Q_0$
Н	Χ	Χ	Χ	Χ	Z

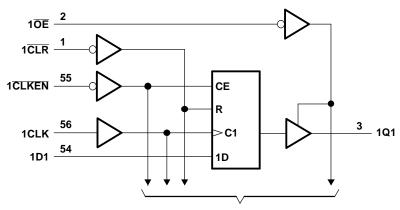
### LOGIC SYMBOL(1)



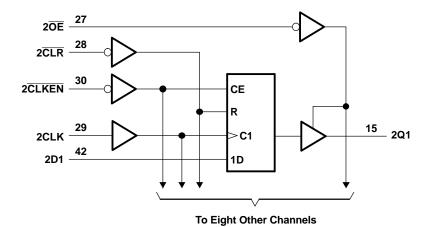
(1) This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



### **LOGIC DIAGRAM (POSITIVE LOGIC)**



To Eight Other Channels



## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	4.6	V
VI	Input voltage range <sup>(2)</sup>	-0.5	4.6	V	
Vo	Output voltage range <sup>(2)(3)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through V <sub>CC</sub> or GND			±100	mA
0	Dooks as the rmal impedence (4)	DGG package		81	°C/W
$\theta_{JA}$	Package thermal impedance (4)	DL package		74	C/VV
T <sub>stg</sub>	Storage temperature range		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> This value is limited to 4.6 V maximum.

<sup>(4)</sup> The package thermal impedance is calculated in accordance with JESD 51.

## SN74ALVCH16823 18-BIT BUS-INTERFACE FLIP-FLOP WITH 3-STATE OUTPUTS





## **Recommended Operating Conditions**(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		1.65	3.6	V
		V <sub>CC</sub> = 1.65 V to 1.95 V	0.65 × V <sub>CC</sub>		
$V_{IH}$	High-level input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V	1.7		V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2		
		V <sub>CC</sub> = 1.65 V to 1.95 V		0.35 × V <sub>CC</sub>	
$V_{IL}$	Low-level input voltage	V <sub>CC</sub> = 2.3 V to 2.7 V		0.7	V
		V <sub>CC</sub> = 2.7 V to 3.6 V		0.8	
V <sub>I</sub>	Input voltage	·	0	V <sub>CC</sub>	V
Vo	Output voltage		0	$V_{CC}$	V
		V <sub>CC</sub> = 1.65 V		-4	
	High lovel output ourrent	V <sub>CC</sub> = 2.3 V		-12	A
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 2.7 V		-12	mA
		V <sub>CC</sub> = 3 V		-24	
		V <sub>CC</sub> = 1.65 V		4	
	Laur laural autout aumant	V <sub>CC</sub> = 2.3 V		12	A
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 2.7 V		12	mA
		V <sub>CC</sub> = 3 V		24	
Δt/Δν	Input transition rise or fall rate	,		10	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

<sup>(1)</sup> All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



SCES038F-JULY 1995-REVISED APRIL 2005

#### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

F	PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN TYP(1)	MAX	UNIT
		I <sub>OH</sub> = -100 μA	1.65 V to 3.6 V	V <sub>CC</sub> – 0.2		
		$I_{OH} = -4 \text{ mA}$	1.65 V	1.2		
		$I_{OH} = -6 \text{ mA}$	2.3 V	2		
$V_{OH}$			2.3 V	1.7		V
		$I_{OH} = -12 \text{ mA}$	2.7 V	2.2		
			3 V	2.4		
		$I_{OH} = -24 \text{ mA}$	3 V	2		
		I <sub>OL</sub> = 100 μA	1.65 V to 3.6 V		0.2	
		I <sub>OL</sub> = 4 mA	1.65 V		0.45	
		I <sub>OL</sub> = 6 mA	2.3 V		0.4	.,
$V_{OL}$			2.3 V		0.7	V
		$I_{OL} = 12 \text{ mA}$	2.7 V		0.4	
		I <sub>OL</sub> = 24 mA	3 V		0.55	
I <sub>I</sub>		$V_I = V_{CC}$ or GND	3.6 V		±5	μΑ
		V <sub>I</sub> = 0.58 V	1.65 V	25		
		V <sub>I</sub> = 1.07 V	1.65 V	-25		
		V <sub>I</sub> = 0.7 V	2.3 V	45		
I <sub>I(hold)</sub>		V <sub>I</sub> = 1.7 V	2.3 V	<b>-45</b>		μΑ
, ,		V <sub>I</sub> = 0.8 V	3 V	75		
		V <sub>I</sub> = 2 V	3 V	<b>-75</b>		
		$V_1 = 0 \text{ to } 3.6 \text{ V}^{(2)}$	3.6 V		±500	
l <sub>OZ</sub>		$V_O = V_{CC}$ or GND	3.6 V		±10	μΑ
I <sub>CC</sub>		$V_I = V_{CC}$ or GND, $I_O = 0$	3.6 V		40	μΑ
$\Delta I_{CC}$		One input at V <sub>CC</sub> – 0.6 V, Other inputs at V <sub>CC</sub> or GND	3 V to 3.6 V		750	μΑ
	Control inputs		0.01/	4.5		
C <sub>i</sub>	Data inputs	$V_{I} = V_{CC}$ or GND	3.3 V	6.5		pF
C <sub>o</sub>	Outputs	$V_O = V_{CC}$ or GND	3.3 V	7		pF

All typical values are at  $V_{CC} = 3.3 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ . This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

## SN74ALVCH16823 18-BIT BUS-INTERFACE FLIP-FLOP WITH 3-STATE OUTPUTS

SCES038F-JULY 1995-REVISED APRIL 2005



#### **Timing Requirements**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1 through Figure 3)

			V <sub>CC</sub> =	1.8 V	V <sub>CC</sub> = 1 ± 0.2	2.5 V 2 V	V <sub>CC</sub> =	2.7 V	V <sub>CC</sub> = ± 0.	3.3 V 3 V	UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>clock</sub>	Clock frequency			(1)		150		150		150	MHz
	Pulse duration	CLR low	(1)		3.3		3.3		3.3		20
t <sub>w</sub>	Pulse duration	CLK high or low	(1)		3.3		3.3		3.3		ns
		CLR inactive	(1)		0.7		0.7		0.8		
	Catura tima	Data low before CLK↑	(1)		1.6		1.6		1.3		
t <sub>su</sub>	Setup time	Daa high before CLK↑	(1)		1.1		1.1		1		ns
		CLKEN low before CLK↑	(1)		1.9		1.9		1.5		
		Data low after CLK↑	(1)		0.5		0.5		0.5		
t <sub>h</sub>	Hold time	Data high after CLK↑	(1)		0.1		0.1		0.8		ns
		CLKEN low after CLK↑	(1)		0.3		0.3		0.4		

<sup>(1)</sup> This information was not available at the time of publication.

#### **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1 through Figure 3)

PARAMETER	PARAMETER FROM		V <sub>CC</sub> = 1.8 V		V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3 ± 0.3	3.3 V 3 V	UNIT
	(INPUT)	(OUTPUT)	MIN	TYP	MIN	MAX	MIN	MAX	MIN	MAX	
f <sub>max</sub>			(1)		150		150		150		MHz
	CLK	0		(1)	1	5.8		5.2	1	4.5	20
<sup>L</sup> pd	CLR	Q		(1)	1	5.4		5.2	1.2	4.6	ns
t <sub>en</sub>	ŌĒ	Q		(1)	1	6		5.7	1	4.8	ns
t <sub>dis</sub>	ŌĒ	Q		(1)	1.1	5.4		4.7	1.3	4.5	ns

<sup>(1)</sup> This information was not available at the time of publication.

#### **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted),  $V_{CC}$  = 3.3 ± 0.3 V,  $C_L$  = 30 pF,  $R_L$  = 500  $\Omega$ 

PARAMETER	FROM	то	$V_{CC} = 3.3 \text{ V} \pm$	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	MIN	MAX	UNII
f <sub>max</sub> <sup>(1)</sup>			250		MHz
+	CLK	Q	1	3.5	ns
<sup>L</sup> pd	CLR	Q	1.2	4.1	115
t <sub>en</sub>	ŌĒ	Q	1	3.8	ns
t <sub>dis</sub>	ŌĒ	Q	1.3	4.5	ns
t <sub>sk(o)</sub> <sup>(1)</sup>			·	0.5	ns

<sup>(1)</sup> Values are characterized but not production tested.





SCES038F-JULY 1995-REVISED APRIL 2005

## **Operating Characteristics**

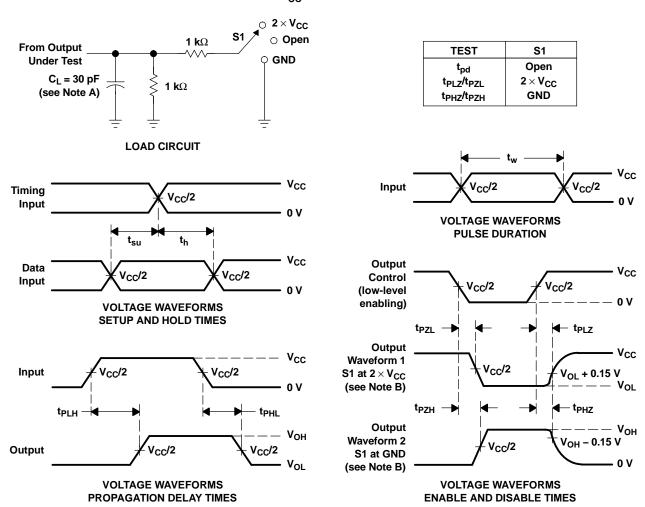
 $T_A = 25^{\circ}C$ 

	PARAMET	ER	TEST CONDITIONS	V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V TYP	UNIT
0	Power dissipation	Outputs enabled	C 50 pF f 40 MHz	(1)	27	30	۲
$C_{pd}$	capacitance	Outputs disabled	$C_L = 50 \text{ pF, f} = 10 \text{ MHz}$	(1)	16	18	pF

<sup>(1)</sup> This information was not available at the time of publication.

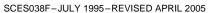


## PARAMETER MEASUREMENT INFORMATION $V_{CC} = 1.8 \text{ V}$



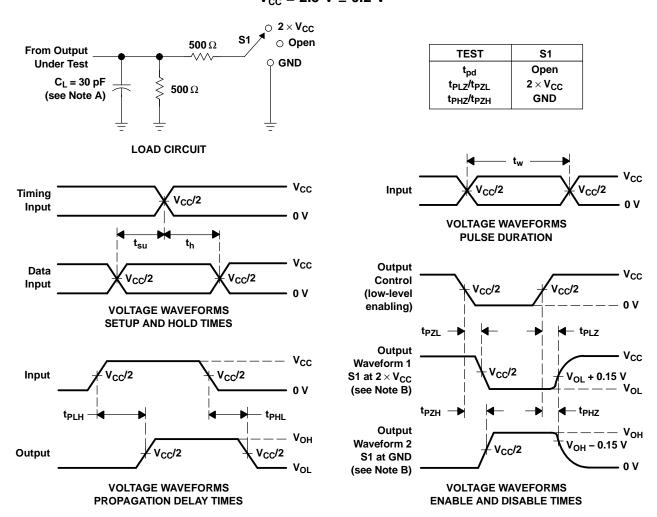
- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_r \leq 2$  ns,  $t_f \leq 2$  ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
  - F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 1. Load Circuit and Voltage Waveforms





## PARAMETER MEASUREMENT INFORMATION $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$



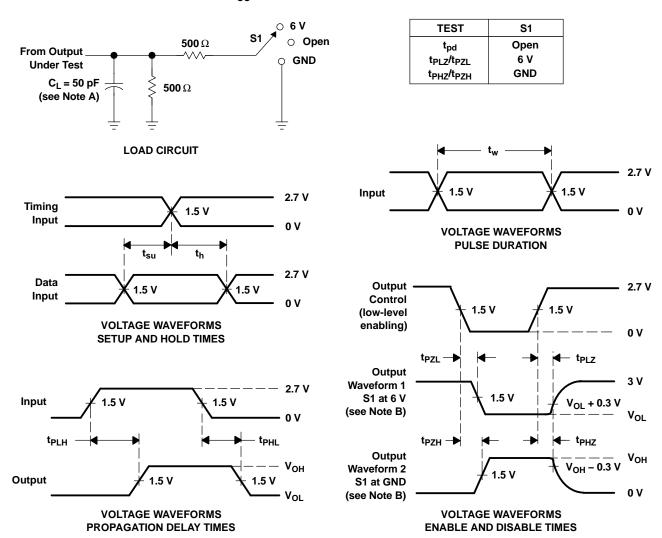
NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50~\Omega$ ,  $t_r \leq$  2 ns,  $t_f \leq$  2 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 2. Load Circuit and Voltage Waveforms



# PARAMETER MEASUREMENT INFORMATION $V_{cc}$ = 2.7 V AND 3.3 V ± 0.3 V



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_0$  = 50  $\Omega$ ,  $t_r \leq$  2.5 ns,  $t_f \leq$  2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 3. Load Circuit and Voltage Waveforms





10-Dec-2020

#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74ALVCH16823DGGR	ACTIVE	TSSOP	DGG	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH16823	Samples
SN74ALVCH16823DGVR	ACTIVE	TVSOP	DGV	56	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	VH823	Samples
SN74ALVCH16823DL	ACTIVE	SSOP	DL	56	20	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH16823	Samples
SN74ALVCH16823DLR	ACTIVE	SSOP	DL	56	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH16823	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE**: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and



## **PACKAGE OPTION ADDENDUM**

10-Dec-2020

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## PACKAGE MATERIALS INFORMATION

www.ti.com 14-Jul-2012

### TAPE AND REEL INFORMATION

#### **REEL DIMENSIONS**



#### **TAPE DIMENSIONS**



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### TAPE AND REEL INFORMATION

#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALVCH16823DGGR	TSSOP	DGG	56	2000	330.0	24.4	8.6	15.6	1.8	12.0	24.0	Q1
SN74ALVCH16823DGVR	TVSOP	DGV	56	2000	330.0	24.4	6.8	11.7	1.6	12.0	24.0	Q1
SN74ALVCH16823DLR	SSOP	DL	56	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1

www.ti.com 14-Jul-2012



\*All dimensions are nominal

7 III dillionio di o Horiilla							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALVCH16823DGGR	TSSOP	DGG	56	2000	367.0	367.0	45.0
SN74ALVCH16823DGVR	TVSOP	DGV	56	2000	367.0	367.0	45.0
SN74ALVCH16823DLR	SSOP	DL	56	1000	367.0	367.0	55.0

### DGV (R-PDSO-G\*\*)

#### **24 PINS SHOWN**

#### **PLASTIC SMALL-OUTLINE**



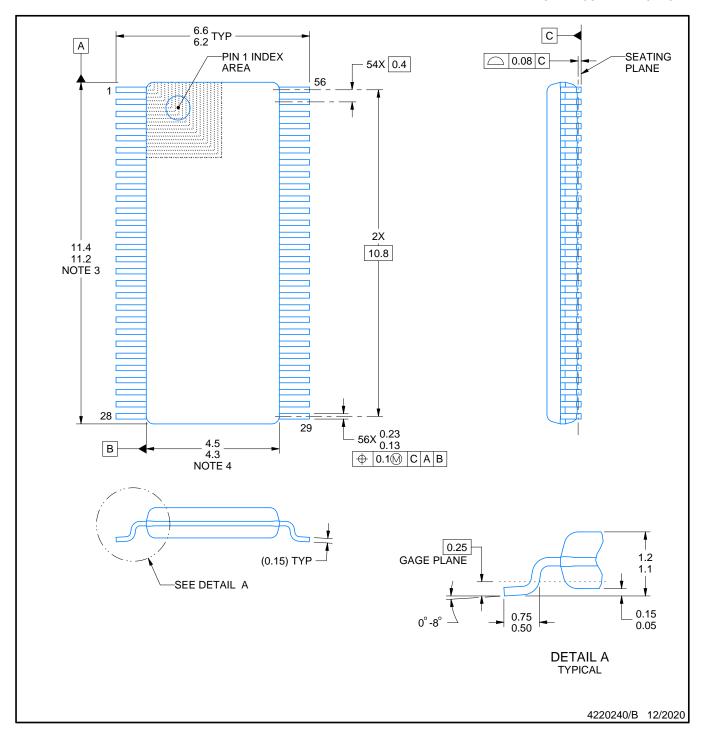
NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194





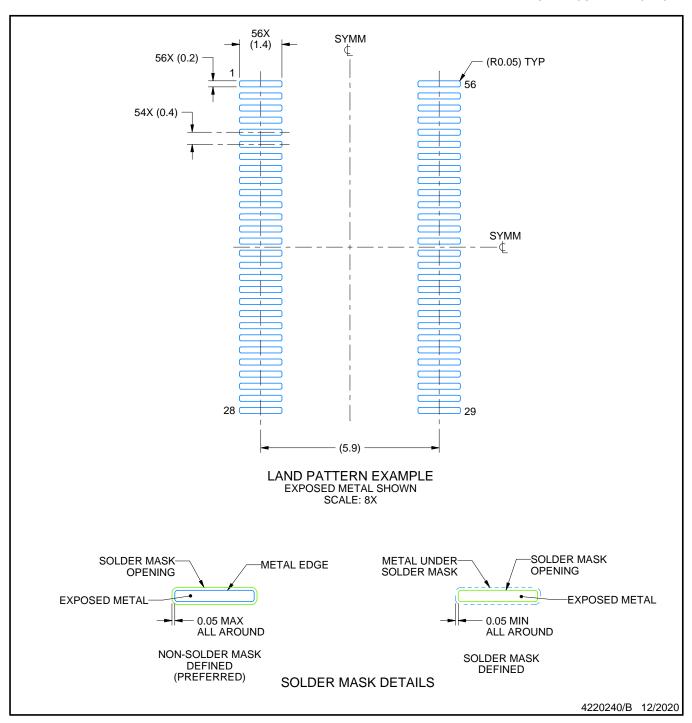
#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-194.



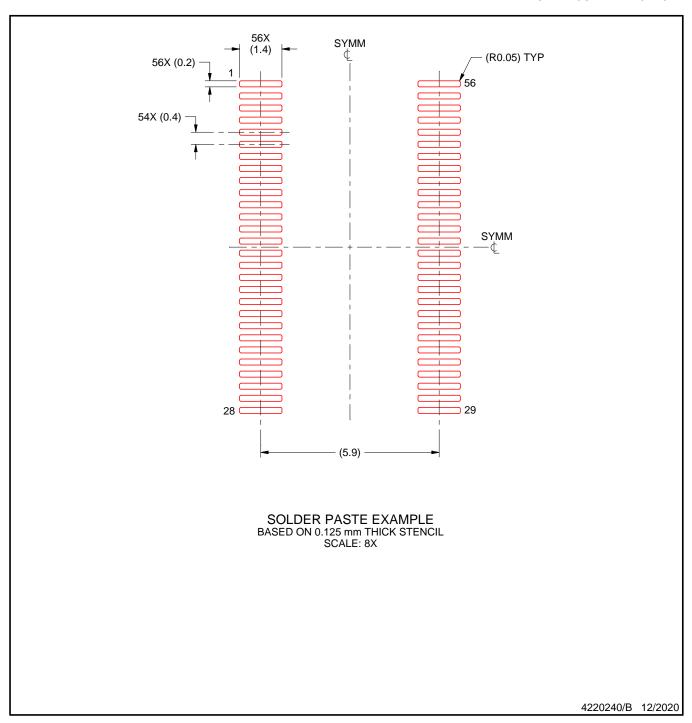


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## DL (R-PDSO-G56)

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.







#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
  4. Reference JEDEC registration MO-153.





NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



#### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

Tl's products are provided subject to Tl's Terms of Sale (<a href="www.ti.com/legal/termsofsale.html">www.ti.com/legal/termsofsale.html</a>) or other applicable terms available either on ti.com or provided in conjunction with such Tl products. Tl's provision of these resources does not expand or otherwise alter Tl's applicable warranties or warranty disclaimers for Tl products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2020, Texas Instruments Incorporated